

MUR3040PT, RURH1540CC, MUR3060PT, RURH1560CC

Data Sheet January 2000 File Number 2774.4

15A, 400V - 600V Ultrafast Dual Diodes

MUR3040PT, RURH1540CC, MUR3060PT, and RURH1560CC are ultrafast dual diodes ($t_{rr} < 55$ ns) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits thus reducing power loss in the switching transistor.

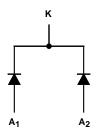
Formerly developmental type TA09905.

Ordering Information

PART NUMBER	PACKAGE	BRAND
MUR3040PT	TO-218AC	MUR3040PT
RURH1540CC	TO-218AC	RURH1540C
MUR3060PT	TO-218AC	MUR3060PT
RURH1560CC	TO-218AC	RURH1560C

NOTE: When ordering, use the entire part number.

Symbol



Features

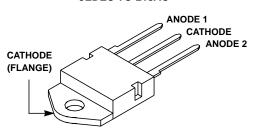
- Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supply
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC TO-218AC



Absolute Maximum Ratings (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

MUR3040PT RURH1540CC	MUR3060PT RURH1560CC	UNITS
400	600	V
400	600	V
400	600	V
15	15	Α
42	30	Α
200	200	Α
100	100	W
20	20	mJ
-55 to 175	-55 to 175	oC
	400 400 400 15 42 200 100 20	RURH1540CC RURH1560CC 400 600 400 600 400 600 15 15 42 30 200 200 100 100 20 20

MUR3040PT, RURH1540CC, MUR3060PT, RURH1560CC

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

	TEST CONDITION	MUR3040PT, RURH1540CC		MUR3060PT, RURH1560CC				
SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 15A	-	-	1.25	-	-	1.5	V
	I _F = 15A, T _C = 150°C	-	-	1.12	-	-	1.2	V
I _R	V _R = 400V	-	-	100	-	-	-	μΑ
	V _R = 600V	-	-	-	-	-	100	μΑ
	$V_R = 400V, T_C = 150^{\circ}C$	-	-	500	-	-	-	μΑ
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	500	μΑ
t _{rr}	I _F = 1A, dI _F /dt = 100A/μs	-	-	55	-	-	55	ns
	I _F = 15A, dI _F /dt = 100A/μs	-	-	60	-	-	60	ns
ta	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	-	30	-	-	30	-	ns
t _b	I _F = 15A, dI _F /dt = 100A/μs	-	17	-	-	20	-	ns
$R_{ heta JC}$		-	-	1.5	-	-	1.5	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time at dI_F/dt = 100A/ μ s (See Figure 6), summation of t_a + t_b .

 t_a = Time to reach peak reverse current at dI_F/dt = 100A/ μ s (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

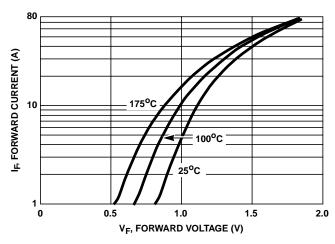


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

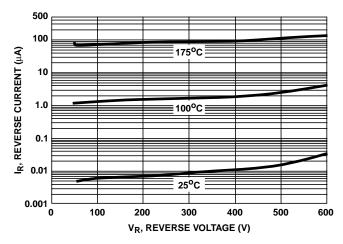


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves

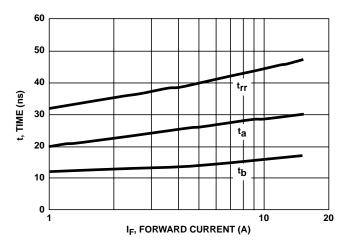


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

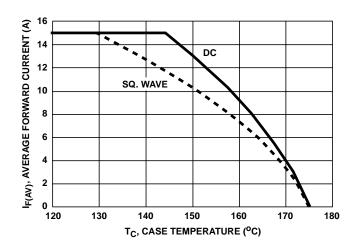


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

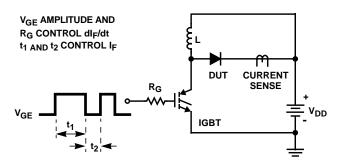


FIGURE 5. t_{rr} TEST CIRCUIT

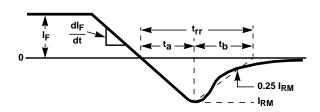


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

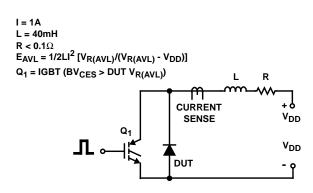


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

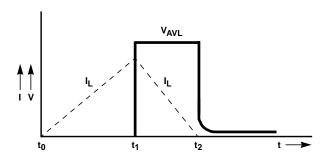


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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